

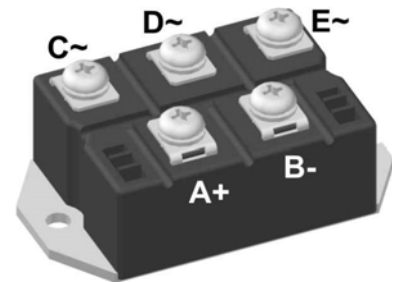
## Standard Rectifier Module

| 3~<br>Rectifier |          |
|-----------------|----------|
| $V_{RRM}$       | = 800 V  |
| $I_{DAV}$       | = 240 A  |
| $I_{FSM}$       | = 2800 A |

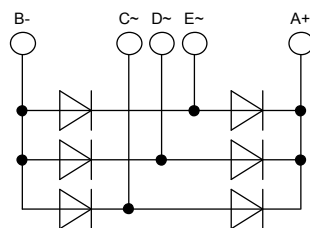
### 3~ Rectifier Bridge

Part number

VUO190-08NO7



 E72873



#### Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

#### Applications:

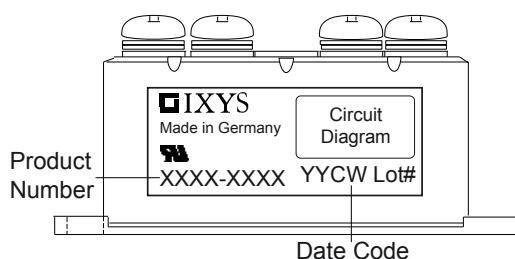
- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

#### Package: PWS-E

- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

| Rectifier  |                                              |                                                              |                                | Ratings                        |      |      |                   |
|------------|----------------------------------------------|--------------------------------------------------------------|--------------------------------|--------------------------------|------|------|-------------------|
| Symbol     | Definition                                   | Conditions                                                   |                                | min.                           | typ. | max. | Unit              |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                                |                                |                                |      | 900  | V                 |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                                |                                |                                |      | 800  | V                 |
| $I_R$      | reverse current                              | $V_R = 800\text{ V}$                                         | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 200  | $\mu\text{A}$     |
|            |                                              | $V_R = 800\text{ V}$                                         | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 3.5  | mA                |
| $V_F$      | forward voltage drop                         | $I_F = 80\text{ A}$                                          | $T_{VJ} = 25^{\circ}\text{C}$  |                                |      | 1.07 | V                 |
|            |                                              | $I_F = 240\text{ A}$                                         |                                |                                |      | 1.36 | V                 |
|            |                                              | $I_F = 80\text{ A}$                                          | $T_{VJ} = 125^{\circ}\text{C}$ |                                |      | 0.96 | V                 |
|            |                                              | $I_F = 240\text{ A}$                                         |                                |                                |      | 1.33 | V                 |
| $I_{DAV}$  | bridge output current                        | $T_C = 110^{\circ}\text{C}$<br>rectangular $d = \frac{1}{3}$ | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 240  | A                 |
| $V_{FO}$   | threshold voltage                            | } for power loss calculation only                            |                                | $T_{VJ} = 150^{\circ}\text{C}$ |      | 0.74 | V                 |
| $r_F$      | slope resistance                             |                                                              |                                |                                |      | 2.4  | m $\Omega$        |
| $R_{thJC}$ | thermal resistance junction to case          |                                                              |                                |                                |      | 0.4  | K/W               |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                              |                                |                                | 0.15 |      | K/W               |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                                   |                                |                                |      | 310  | W                 |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$             | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 2.80 | kA                |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$            | $V_R = 0\text{ V}$             |                                |      | 3.03 | kA                |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$             | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 2.38 | kA                |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$            | $V_R = 0\text{ V}$             |                                |      | 2.57 | kA                |
| $I^2t$     | value for fusing                             | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$             | $T_{VJ} = 45^{\circ}\text{C}$  |                                |      | 39.2 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$            | $V_R = 0\text{ V}$             |                                |      | 38.1 | kA <sup>2</sup> s |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$             | $T_{VJ} = 150^{\circ}\text{C}$ |                                |      | 28.3 | kA <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$            | $V_R = 0\text{ V}$             |                                |      | 27.5 | kA <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$                       |                                |                                | 133  |      | pF                |

| Package PWS-E |                                                              |                      | Ratings |      |      |      |
|---------------|--------------------------------------------------------------|----------------------|---------|------|------|------|
| Symbol        | Definition                                                   | Conditions           | min.    | typ. | max. | Unit |
| $I_{RMS}$     | RMS current                                                  | per terminal         |         |      | 250  | A    |
| $T_{stg}$     | storage temperature                                          |                      | -40     |      | 125  | °C   |
| $T_{VJ}$      | virtual junction temperature                                 |                      | -40     |      | 150  | °C   |
| Weight        |                                                              |                      |         | 284  |      | g    |
| $M_D$         | mounting torque                                              |                      | 4.25    |      | 5.75 | Nm   |
| $M_T$         | terminal torque                                              |                      | 4.25    |      | 5.75 | Nm   |
| $d_{Spp/App}$ | creepage distance on surface   striking distance through air | terminal to terminal | 12.0    |      |      | mm   |
| $d_{Spb/Apb}$ |                                                              | terminal to backside | 26.0    |      |      | mm   |
| $V_{ISOL}$    | isolation voltage                                            | t = 1 second         | 3000    |      |      | V    |
|               |                                                              | t = 1 minute         | 2500    |      |      | V    |

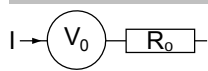


| Ordering | Part Number  | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|--------------|--------------------|---------------|----------|----------|
| Standard | VUO190-08NO7 | VUO190-08NO7       | Box           | 5        | 462489   |

### Equivalent Circuits for Simulation

\* on die level

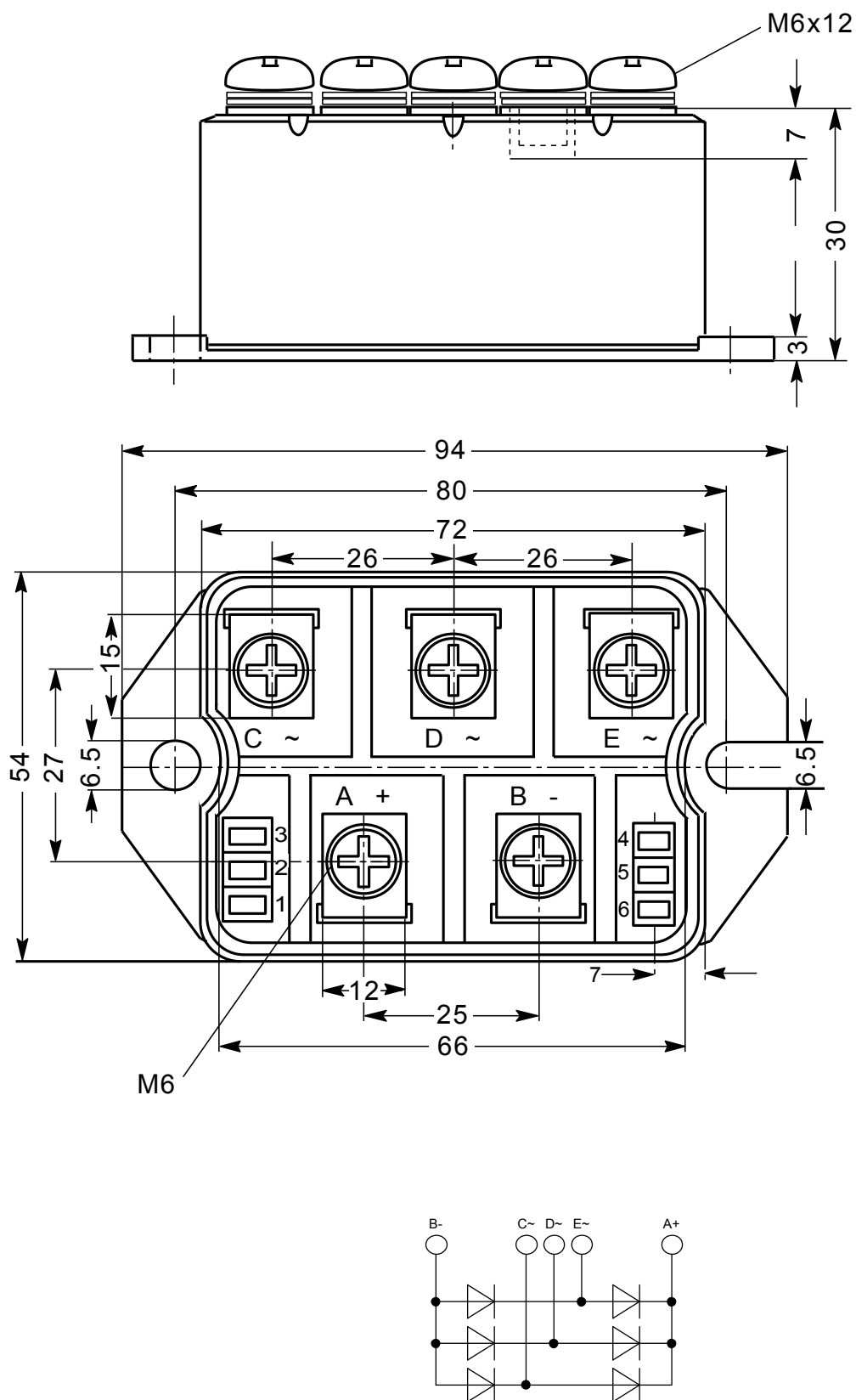
$T_{VJ} = 150^\circ\text{C}$



Rectifier

|             |                    |      |    |
|-------------|--------------------|------|----|
| $V_{0\max}$ | threshold voltage  | 0.74 | V  |
| $R_{0\max}$ | slope resistance * | 1.2  | mΩ |

## Outlines PWS-E



## Rectifier

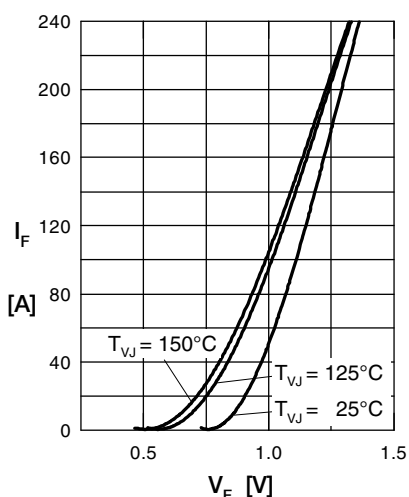


Fig. 1 Forward current vs. voltage drop per diode

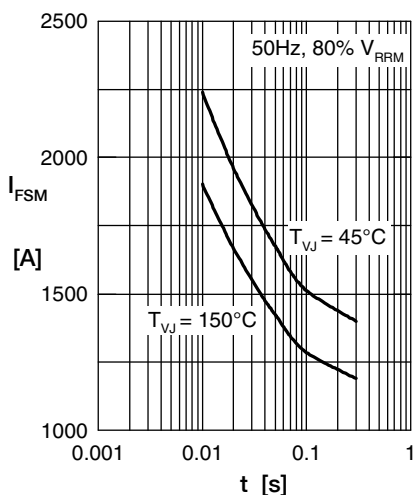


Fig. 2 Surge overload current vs. time per diode

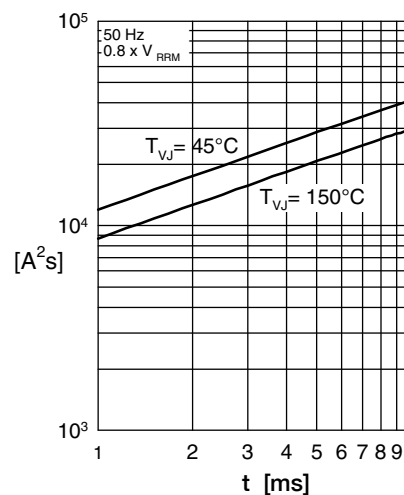


Fig. 3  $I^2t$  vs. time per diode

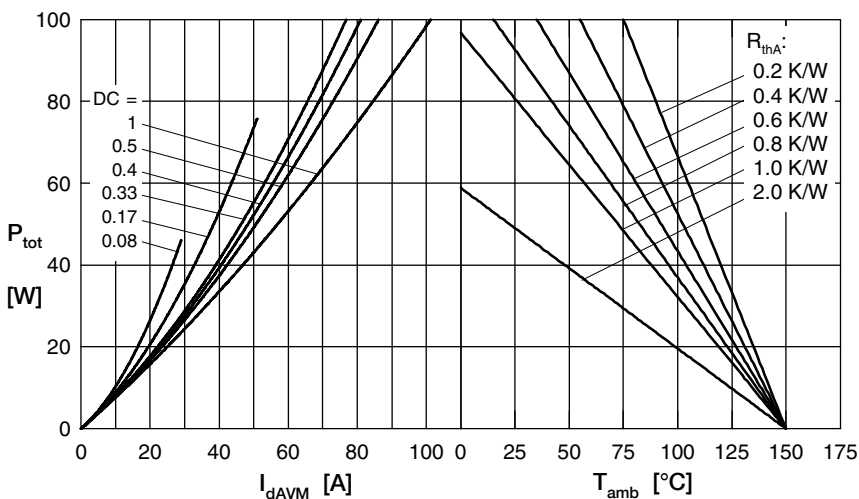


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

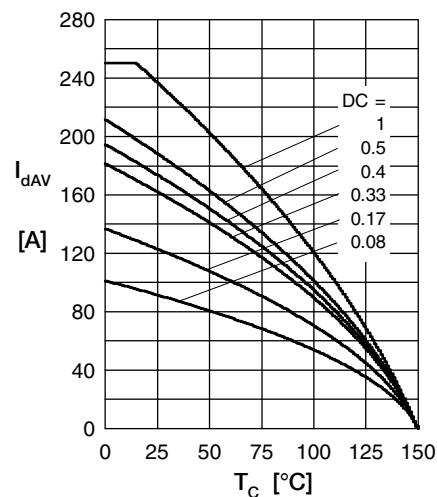


Fig. 5 Max. forward current vs. case temperature per diode

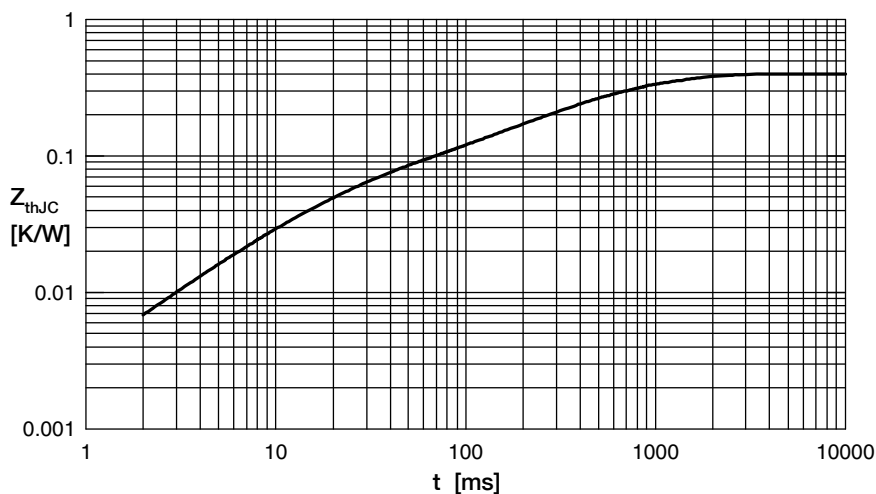


Fig. 6 Transient thermal impedance junction to case vs. time per diode

| $R_i$ | $t_i$ |
|-------|-------|
| 0.050 | 0.02  |
| 0.003 | 0.01  |
| 0.100 | 0.225 |
| 0.177 | 0.8   |
| 0.070 | 0.58  |